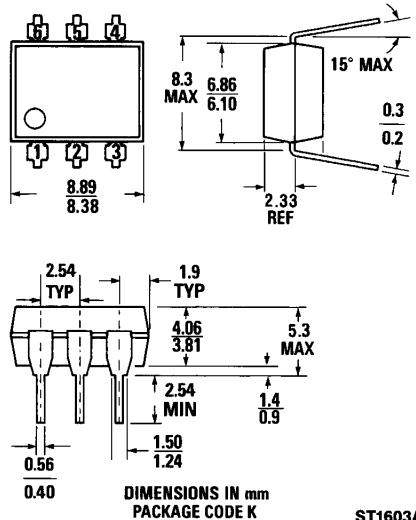




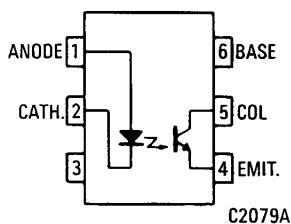
## PHOTOTRANSISTOR OPTOCOUPLES

**MOC8111  
MOC8112  
MOC8113**

### PACKAGE DIMENSIONS



ST1603A



Equivalent Circuit

### DESCRIPTION

The MOC series consists of a Gallium Arsenide IRED coupled with an NPN phototransistor.

### FEATURES

- High isolation voltage  
5300 VAC RMS—1 minute  
7500 VAC PEAK—1 minute
- High  $BV_{CEO}$  minimum 70 volts
- Current transfer ratio in selected groups:  
MOC8111: 20% min.  
MOC8112: 50% min.  
MOC8113: 100% min.
- Maximum switching time in saturation specified
- Underwriters Laboratory (UL) recognized File #E90700

### APPLICATIONS

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs
- Appliance sensor systems
- Industrial controls

### ABSOLUTE MAXIMUM RATINGS

#### TOTAL PACKAGE

Storage temperature .....	-55°C to 150°C
Operating temperature .....	-55°C to 100°C
Lead temperature (soldering, 10 sec) .....	260°C
Total package power dissipation @ 25°C (LED plus detector) .....	260 mW
Derate linearly from 25°C .....	3.5 mW/°C

#### INPUT DIODE

Forward DC current .....	90 mA
Reverse voltage .....	6 V
Peak forward current (1 μs pulse, 300 pps) .....	3.0 A
Power dissipation 25°C ambient .....	135 mW
Derate linearly from 25°C .....	1.8 mW/°C

#### OUTPUT TRANSISTOR

Power dissipation @ 25°C .....	200 mW
Derate linearly from 25°C .....	2.67 mW/°C



## PHOTOTRANSISTOR OPTOCOUPLES

### ELECTRO-OPTICAL CHARACTERISTICS (25°C Temperature Unless Otherwise Specified)

#### INDIVIDUAL COMPONENT CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
<b>INPUT DIODE</b>						
Forward voltage	$V_F$		1.3	1.50	V	$I_F = 60 \text{ mA}$
Forward voltage temp. coefficient	$\frac{\Delta V_F}{\Delta T_A}$		-1.8		mV/°C	
Reverse voltage	$V_R$	6.0	15		V	$I_R = 10 \mu\text{A}$
Junction capacitance	$C_J$		50		pF	$V_F = 0 \text{ V}, f = 1 \text{ MHz}$
			65		pF	$V_F = 1 \text{ V}, f = 1 \text{ MHz}$
Reverse leakage current	$I_R$	.35	10		$\mu\text{A}$	$V_R = 3.0 \text{ V}$
<b>OUTPUT TRANSISTOR</b>						
Breakdown voltage Collector to emitter	$BV_{CEO}$	70			V	$I_C = 1.0 \text{ mA}, I_F = 0$
Emitter to collector Leakage current	$BV_{ECO}$	7			V	$I_E = 100 \mu\text{A}, I_F = 0$
Collector to emitter	$I_{CEO}$		5	50	nA	$V_{CE} = 10 \text{ V}, I_F = 0$
Capacitance Collector to emitter			8		pF	$V_{CE} = 0, f = 1 \text{ MHz}$

#### TRANSFER CHARACTERISTICS

DC CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Current Transfer Ratio, collector to emitter MOC8111	CTR				%	$I_F = 10 \text{ mA}; V_{CE} = 5 \text{ V}$
		20				
MOC8112		50				
MOC8113		100				
Saturation voltage	$V_{CE(SAT)}$		0.27	.40	V	$I_F = 10 \text{ mA}; I_C = 2.5 \text{ mA}$

#### TRANSFER CHARACTERISTICS

AC CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
<b>SWITCHING TIMES</b>						
Non-saturated Turn-on time	$t_{on}$		6.0	10	$\mu\text{s}$	$R_L = 100 \Omega; I_C = 2 \text{ mA}; V_{CC} = 10 \text{ V}$
Turn-off time	$t_{off}$		5.5	10	$\mu\text{s}$	See Fig. 10.



## PHOTOTRANSISTOR OPTOCOUPLES

### ELECTRO-OPTICAL CHARACTERISTICS (25°C Temperature Unless Otherwise Specified) (Cont'd)

#### TRANSFER CHARACTERISTICS (Cont'd)

AC CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
<b>SATURATED SWITCHING TIMES</b>						
Turn-on time	$t_{on}$					
MOC8111		3.0	5.5		$\mu\text{s}$	$I_F = 20 \text{ mA}, V_{CE} = 0.4 \text{ V}$
MOC8112, MOC8113		4.2	8.0		$\mu\text{s}$	$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$
Rise-time	$t_r$					
MOC8111		2.0	4.0		$\mu\text{s}$	$I_F = 20 \text{ mA}, V_{CE} = 0.4 \text{ V}$
MOC8112, MOC8113		3.0	6.0		$\mu\text{s}$	$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$
Turn-off time	$t_{off}$					
MOC8111		18	34		$\mu\text{s}$	$I_F = 20 \text{ mA}, V_{CE} = 0.4 \text{ V}$
MOC8112, MOC8113		23	39		$\mu\text{s}$	$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$
Fall-time	$t_f$					
MOC8111		11	20		$\mu\text{s}$	$I_F = 20 \text{ mA}, V_{CE} = 0.4 \text{ V}$
MOC8112, MOC8113		14	24		$\mu\text{s}$	$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$

### ISOLATION CHARACTERISTICS

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Isolation voltage	$V_{iso}$	5300			$V_{AC}$ RMS	$I_{IO} \leq 1 \mu\text{A}, 1 \text{ minute}$
	$V_{iso}$	7500			$V_{AC}$ PEAK	$I_{IO} \leq 1 \mu\text{A}, 1 \text{ minute}$
Isolation resistance	$R_{iso}$	$10^{11}$			ohms	$V_{IO} = 500 \text{ VDC}$
Isolation capacitance	$C_{iso}$		0.5		pF	$f = 1 \text{ MHz}$

### ELECTRICAL CHARACTERISTIC CURVES (25°C Free Air Temperature Unless Otherwise Specified)

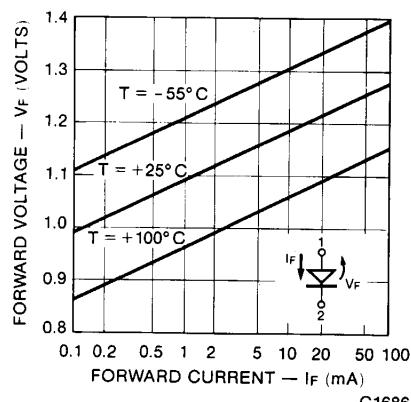


Fig. 1. Forward Voltage vs.  
Current

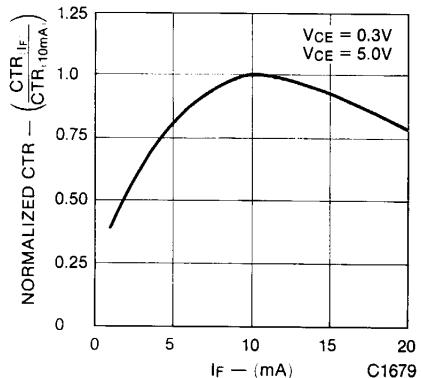


Fig. 2. Normalized CTR vs.  
Forward Current



## PHOTOTRANSISTOR OPTOCOUPLES

### ELECTRO-OPTICAL CHARACTERISTICS (25°C Temperature Unless Otherwise Specified) (Cont'd)

#### TRANSFER CHARACTERISTICS (Cont'd)

AC CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
<b>SATURATED SWITCHING TIMES</b>						
Turn-on time	$t_{on}$					
MOC8111		3.0	5.5		$\mu\text{s}$	$I_F = 20 \text{ mA}, V_{CE} = 0.4 \text{ V}$
MOC8112, MOC8113		4.2	8.0		$\mu\text{s}$	$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$
Rise-time	$t_r$					
MOC8111		2.0	4.0		$\mu\text{s}$	$I_F = 20 \text{ mA}, V_{CE} = 0.4 \text{ V}$
MOC8112, MOC8113		3.0	6.0		$\mu\text{s}$	$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$
Turn-off time	$t_{off}$					
MOC8111		18	34		$\mu\text{s}$	$I_F = 20 \text{ mA}, V_{CE} = 0.4 \text{ V}$
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Isolation resistance	$R_{iso}$	$10^{11}$			ohms	$V_{IO} = 500 \text{ VDC}$
Isolation capacitance	$C_{iso}$		0.5		pF	$f = 1 \text{ MHz}$

### ELECTRICAL CHARACTERISTIC CURVES (25°C Free Air Temperature Unless Otherwise Specified)

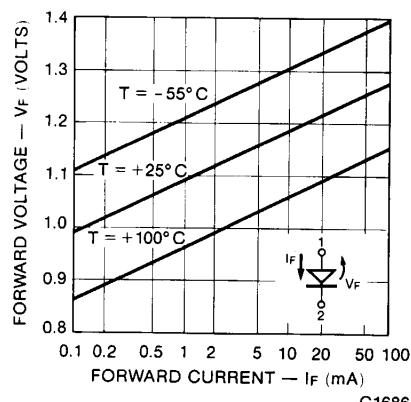


Fig. 1. Forward Voltage vs.  
Current

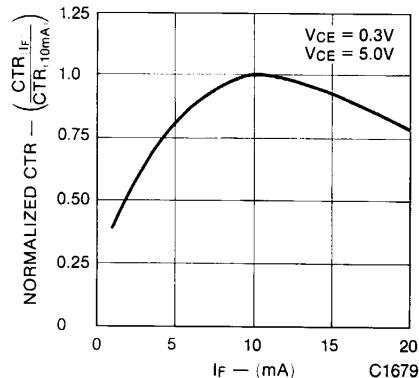


Fig. 2. Normalized CTR vs.  
Forward Current



## PHOTOTRANSISTOR OPTOCOUPERS

### ELECTRICAL CHARACTERISTIC CURVES

(25°C Free Air Temperature Unless Otherwise Specified) (Cont'd)

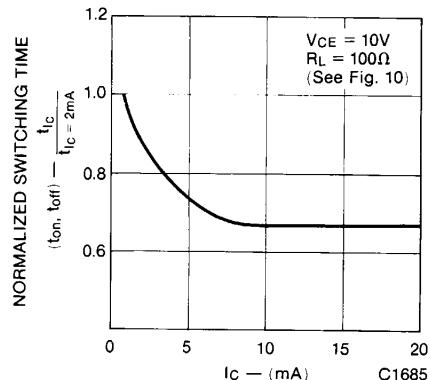


Fig. 5. Switching Time  
vs. IC

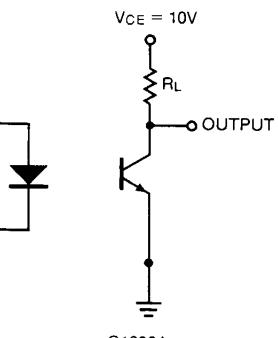


Fig. 6. Switching Time  
Test Circuit

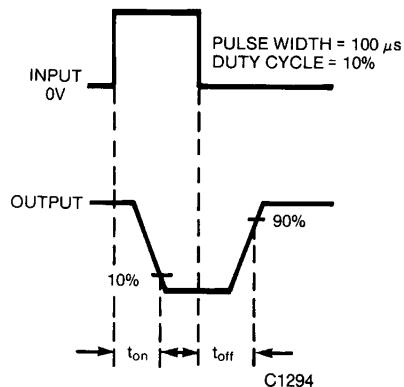


Fig. 7. Switching Time Waveforms